TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π–MOSV)

2SK2662

DC-DC Converter, Relay Drive and Motor Drive Applications

• Low drain-source ON resistance : $R_{DS (ON)} = 1.35 \Omega (typ.)$

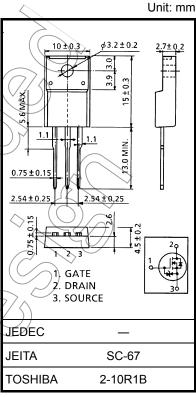
High forward transfer admittance : |Y_{fs}| = 4.0 S (typ.)

Low leakage current : I_{DSS} = 100 μA (max) (V_{DS} = 500 V)

• Enhancement mode : $V_{th} = 2.0 \text{ to } 4.0 \text{ V } (V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA})$

Absolute Maximum Ratings (Ta = 25°C)

Characteris	stics	Symbol	Rating	Unit
Drain-source voltage		V _{DSS}	500	A
Drain-gate voltage (Ro	$g_{S} = 20 \text{ k}\Omega$	V_{DGR}	500	y
Gate-source voltage		V _{GSS}	±30	> V
Drain current	DC (Note 1)	I _D	5	Α
	Pulse (Note 1)	I _{DP}	20	A
Drain power dissipation	r (Tc = 25°C)	P _D <	35	W
Single pulse avalanche	energy (Note 2)	EAS	180) m
Avalanche current		IAR)) 5	Α
Repetitive avalanche e	nergy (Note 3)	(EAR \	3.5	mJ
Channel temperature		Tch	150	7,¢
Storage temperature ra	inge ((√T _{stg}	-55 to 150)°C



Weight: 1.9 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	Rth (ch-c)	3.57	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	62.5	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: $V_{DD} = 90~V,~T_{ch} = 25^{\circ}C$ (initial), L = 12.2 mH, R_G = 25 $\Omega,~I_{AR} = 5~A$

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device.

Please handle with caution.

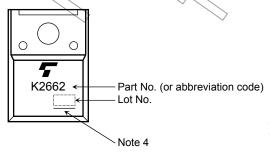
Electrical Characteristics (Ta = 25°C)

Charac	eteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cu	rrent	I _{GSS}	V _{GS} = ±25 V, V _{DS} = 0 V	_	_	±10	μΑ
Gate-source bre	eakdown voltage	V (BR) GSS	I _G = ±10 μA, V _{DS} = 0 V	±30	_	_	V
Drain cut-off cui	rrent	I _{DSS}	V _{DS} = 500 V, V _{GS} = 0 V		_	100	μA
Drain-source br	eakdown voltage	V _{(BR) DSS}	I _D = 10 mA, V _{GS} = 0 V	500		_	V
Gate threshold v	oltage	V_{th}	V _{DS} = 10 V, I _D = 1 mA	2.0) >_	4.0	V
Drain-source Ol	N resistance	R _{DS} (ON)	V _{GS} = 10 V, I _D = 2.5 A	>_	1.35	1.50	Ω
Forward transfer	admittance	Y _{fs}	V _{DS} = 10 V, I _D = 2.5 A	2.5	4.0	_	S
Input capacitano	e	C _{iss}		_	780	_	
Reverse transfer capacitance		C _{rss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	^ —	60	_	pF
Output capacitance		Coss		_	200	_	
Switching time	Rise time	t _r	V _{GS} _{OV}	- (12	>	
	Turn-on time	t _{on}	R_L		25) –	
	Fall time	t _f	V _{DD} ≒225V	2	15	_	ns
	Turn-off time	t _{off}	Duty $\leq 1\%$, $t_{\rm W} = 10 \mu \rm s$) –	60	_	
Total gate charg plus gate-drain)		Qg			17		
Gate-source ch	arge	Q _{gs}	$V_{DD} \approx 400 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 5 \text{ A}$	_	11	_	nC
Gate-drain ("mil	ler") Charge	Qgd		_	6	_	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	1 _{DR}		_	_	5	Α
Pulse drain reverse current (Note 1)	I _{DRP}	_	_	_	20	Α
Forward voltage (diode)	V _{DSF}	I _{DR} = 5 A, V _{GS} = 0 V	_	_	-1.7	V
Reverse recovery time	t _{rr}	I _{DR} = 5 A, V _{GS} = 0 V		1400		ns
Reverse recovery charge	Q _{rr}	dl _{DR} / dt = 100 A / μs	_	9		μC

Marking



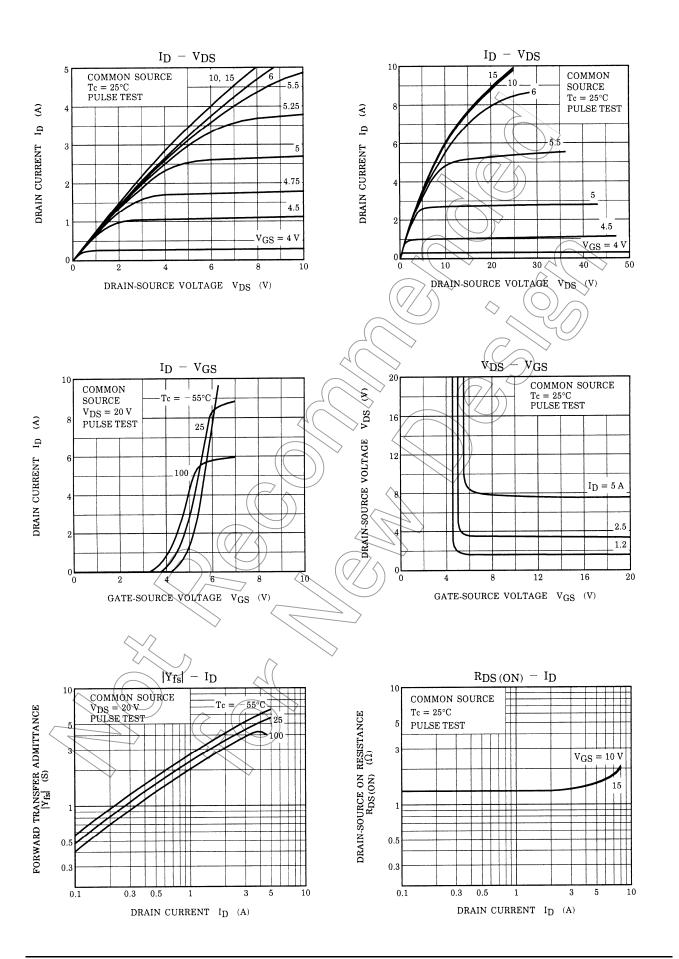
Note 4: A line under a Lot No. identifies the indication of product Labels.

Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

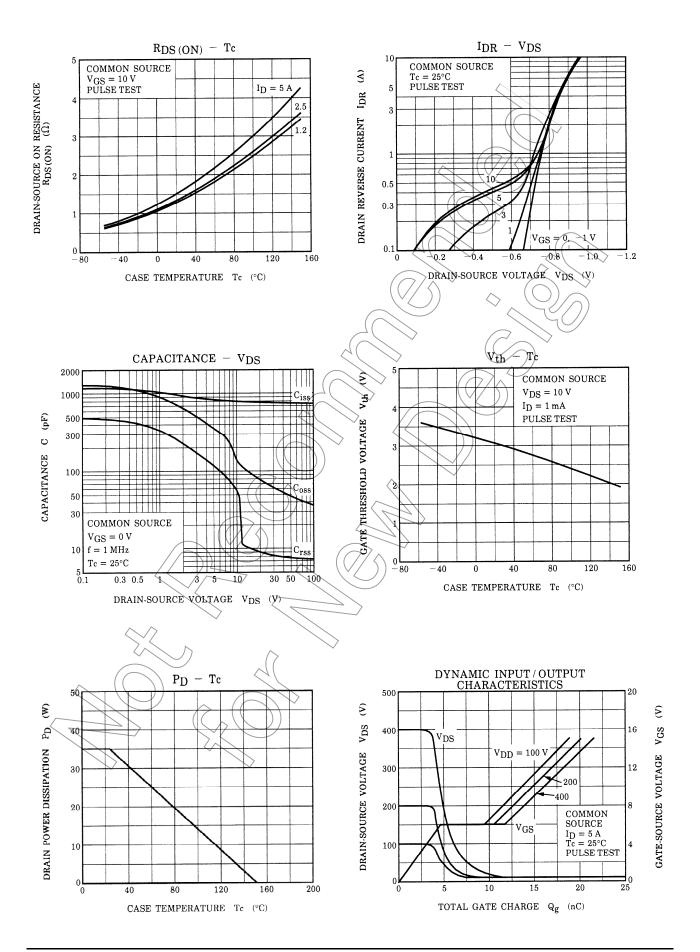
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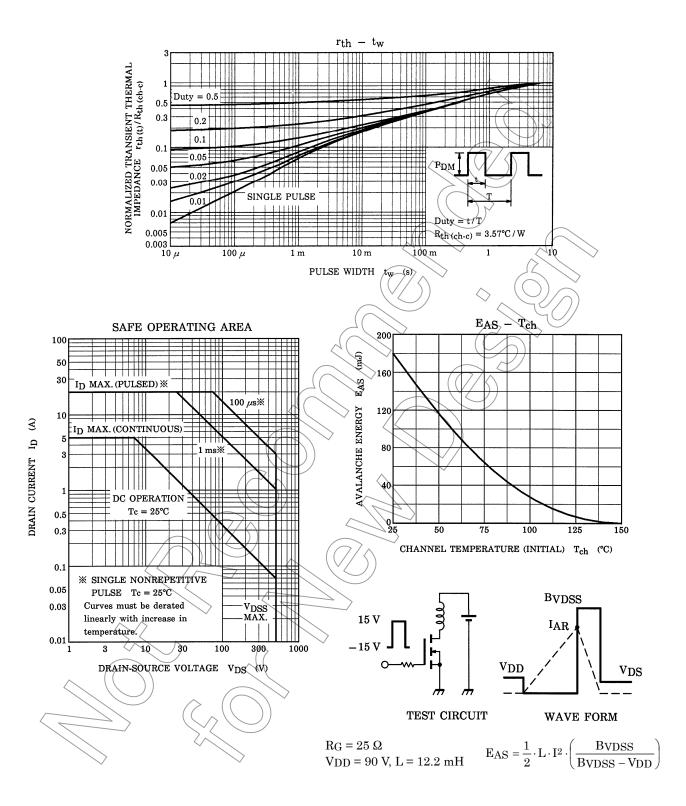
certain hazardous substances in electrical and electronic equipment.

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